

Description

The AR0534S2 is a low capacitance TVS arrays, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The AR0534S2 complies with the IEC 61000-4-2 (ESD) standard with ±15kV air and ±8kV contact discharge. It is assembled into a 6-lead SOT23-6 lead-free package. The leads are finished with lead-free matte tin. Each device will protect up to four high-speed lines. The combination of small size, low capacitance, and high surge capability makes them ideal for use in applications such as Ethernet, USB 2.0, and video interfaces.

Features

Low capacitance: 0.8pF typical (I/O to I/O)

Ultra low leakage: nA levelLow operating voltage: 5V

Low clamping voltage

Up to 4 lines and one power line protects

Complies with following standards:

IEC 61000-4-2 (ESD) immunity test
Air discharge: ±30kV
Contact discharge: ±25kV

- IEC61000-4-4 (EFT) 40A (5/50ns)

- IEC61000-4-5 (Lightning) 8A (8/20µs)

RoHS Compliant

Mechanical Characteristics

Package: SOT23-6Lead Finish: Matte Tin

Case Material: "Green" Molding CompoundUL Flammability Classification Rating 94V-0

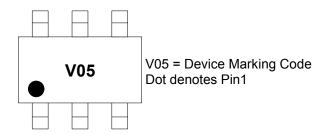
• Terminal Connections: See Diagram Below

Marking Information: See Below

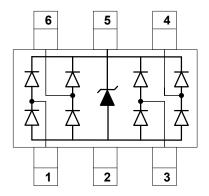
Applications

- USB 2.0 power and data line
- · Monitors and flat panel displays
- Set-top box and digital TV
- Digital video interface (DVI)
- Notebook Computers
- SIM Ports
- Gigabit Ethernet
- IEEE 1394 firewire ports

Marking Information



Dimensions and Pin Configuration



Circuit and Pin Schematic

Ordering Information

Part Number	Packaging	Reel Size
AR0534S2	3000/Tape & Reel	7 inch



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	160	W
Peak Pulse Current (8/20µs)	IPP	8	Α
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)	VESD	±25	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

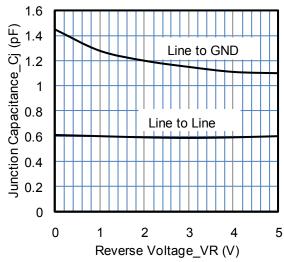
Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	Pin 5 to Pin 2
Breakdown Voltage	VBR	6			V	IT = 1mA, Pin 5 to Pin 2
Reverse Leakage Current	I _R			0.5	μA	VRWM = 5V, Pin 5 to Pin 2
Forward Voltage	VF			1.2	V	IF = 15mA
Clamping Voltage	Vc			12	V	IPP = 1A (8 x 20μs pulse), any I/O pin to ground
Clamping Voltage	Vc			20	V	IPP = 8A (8 x 20μs pulse), any I/O pin to ground
Junction Capacitance	Cı			0.8	pF	VR = 0V, f = 1MHz, between I/O pins
Junction Capacitance	Сл			1.5	pF	VR = 0V, f = 1MHz, any I/O pin to ground

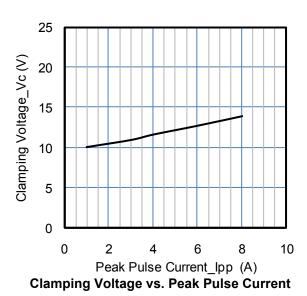
Note 1: I/O pins are Pin 1, 3, 4 and 6

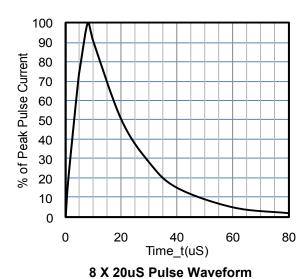


Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



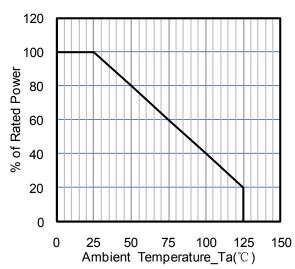
Junction Capacitance vs. Reverse Voltage



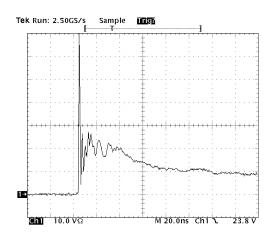


0.01 1 10 100 1000 Pulse Duration tp (us)

Peak Pulse Power vs. Pulse Time



Power Derating Curve

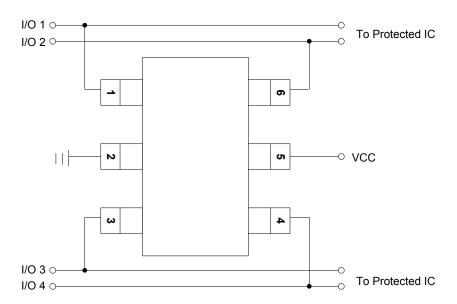


ESD Clamping Voltage 8 kV Contact per IEC61000-4-2

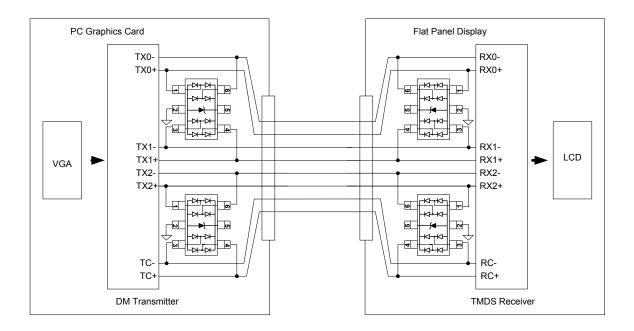


Typical Application

The AR0534S2 is designed to protect four data lines from transient over-voltages by clamping them to fixed refer ence. When the voltage on the protected line exceeds the reference voltage (plus diode VF) the steering diodes are forward biased, conducting the transient current away from the sensitive circuitry. Data lines are connected at pins 1, 3, 4 and 6. The negative reference (REF1) is connected at pin 2. This pin should be connected directly to a ground plane on the board for best results. The path length is kept as short as possible to minimize parasitic inductance. The positive reference (REF2) is connected at pin 5.

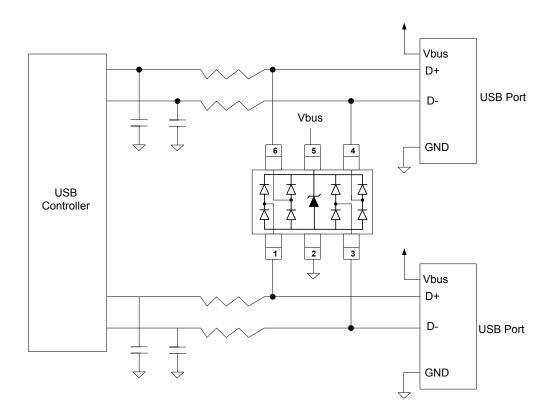


AR0534S2 on Digital Visual Interface (DVI) Application

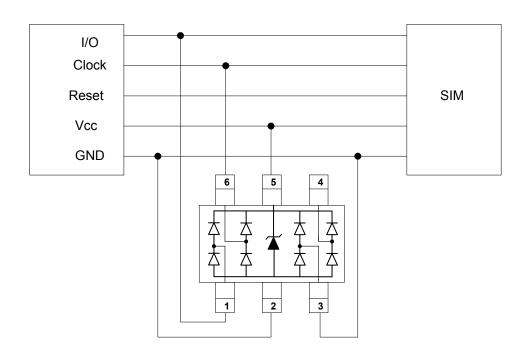




AR0534S2 on USB Port Application



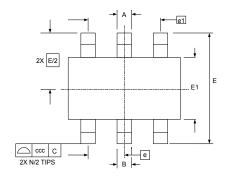
AR0534S2 on SIM Port Application

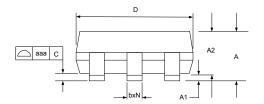


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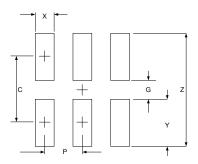
SOT23-6 Package Outline Drawing





	DIMENSIONS					
	MILLIMETERS			INCHES		
SYM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.90		1.45	0.035		0.057
A1	0.00		0.15	0.000		0.006
A2	0.90	1.15	1.30	0.035	0.045	0.051
b	0.25		0.50	0.010		0.020
С	0.08		0.22	0.003		0.009
D	2.80	2.90	3.10	0.110	0.114	0.122
E1	1.50	1.60	1.75	0.060	0.063	0.069
Е	2.80 BSC			0.110 BSC		
е	0.95 BSC			0.037 BSC		
e1	1.90 BSC			0.075 BSC		
N	6			6		
aaa	0.10			0.004		
ccc	0.20				0.008	

Suggested Land Pattern



SYM	DIMENSIONS			
	MILLIMETERS	INCHES		
С	2.50	0.098		
G	1.40	0.055		
Р	0.95	0.037		
Х	0.60	0.024		
Υ	1.10	0.043		
Z	3.60	0.141		

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